


[Home](#) > [2N3629 \(#23120\)](#)

Products

- ▶ [Product Directory](#)
- ▶ [Applications Directory](#)
- ▶ [Parametric Search](#)

2N3629 (#23120)

Overview

Diagrams

Electrical Rating	Symbol	Min	Typ	Max	Unit
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$			1.50	V
DC Current Gain	HFE	40.00			

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	$V_{BR(CBO)}$			75.00	V
Collector Current (dc)	I_C			5.00	A
Collector-Emitter Voltage (Base Open)	V_{CEO}			40.00	V
Emitter-Base Voltage (Collector Open)	V_{EBO}			4.00	V
Power Dissipation, Total	P_T			30.00	W

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